

**Product data sheet** 

### 1. General description

AC Thyristor power switch in a SOT54 plastic package with self-protective capabilities against low and high energy transients

### 2. Features and benefits

- Exclusive negative gate triggering •
- Full cycle AC conduction
- High noise immunity •
- Remote gate separates the gate driver from the effects of the load current •
- Very sensitive gate for lowest gate trigger current
- Safe clamping of low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients •

### 3. Applications

- Fan motor circuits •
- Pump motor circuits
- Lower-power highly inductive, resistive and safety loads •

### 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 71 °C; <u>Fig. 1</u>	-	-	0.8	А
Static chara	acteristics		·			
I <sub>GT</sub>	gate trigger current	$V_D$ = 12 V; I <sub>T</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA

AC Thyristor power switch

## 5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	СМ	common		LD				
2	G gate							
3	LD	load	321 TO-92 (SOT54)	G <b>—•</b> □[́_ ↓ CM 001aaj924				

# 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
ACT108-600D	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
ACT108-600D/DG	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

ACT108-600D

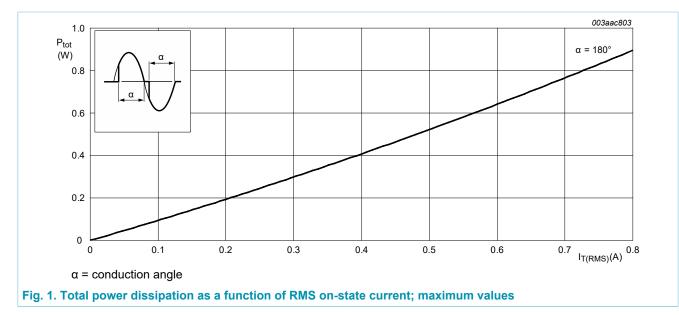
AC Thyristor power switch

# 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

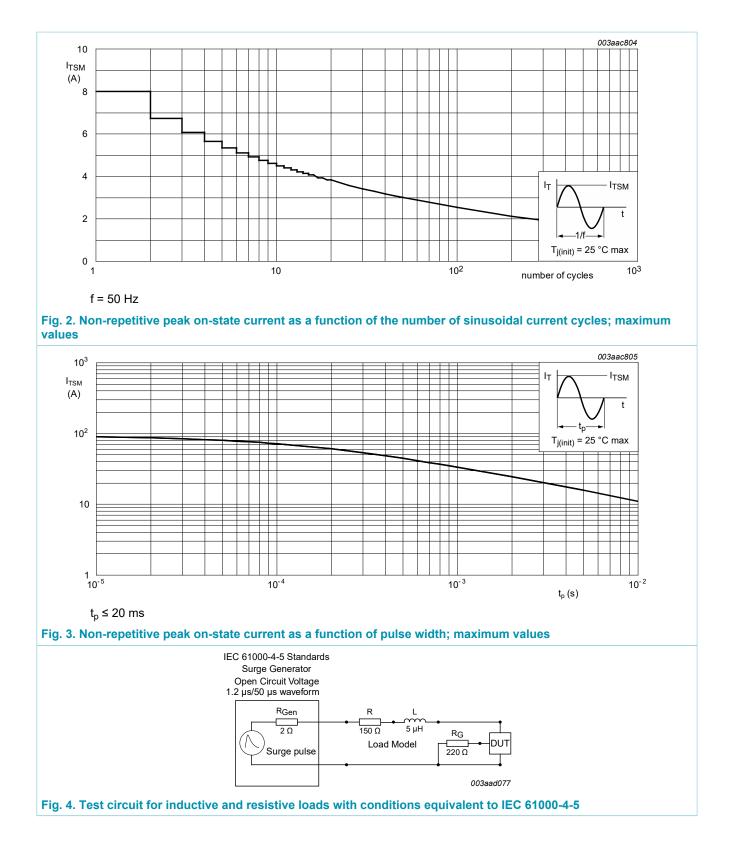
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 71 °C; <u>Fig. 1</u>	-	0.8	А
I <sub>TSM</sub>	non-repetitive peak on-	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	8.8	А
	state current	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 20 ms; Fig. 2; Fig. 3	-	8	A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	0.32	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 10 mA	-	50	A/µs
I <sub>GM</sub>	peak gate current	t = 20 µs	-	1	А
V <sub>GM</sub>	peak gate voltage		-	15	V
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V <sub>PP</sub>	peak pulse voltage	T <sub>j</sub> = 25 °C; non-repetitive, off-state; <u>Fig. 4</u>	-	2	kV



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# ACT108-600D

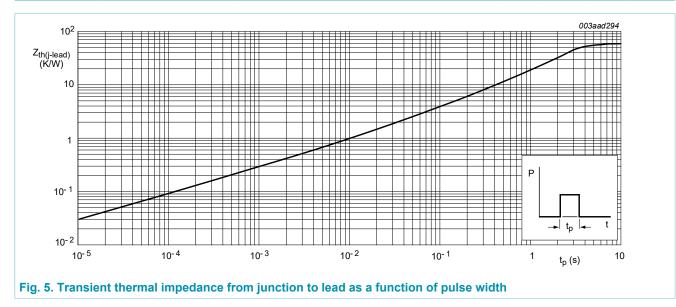
#### AC Thyristor power switch



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### 8. Thermal characteristics

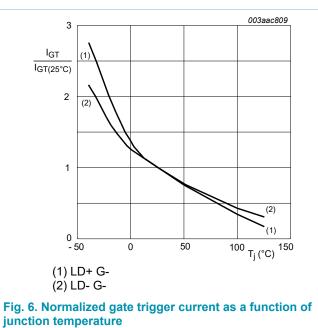
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle with heatsink compound; Fig. 5	-	-	60	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	full cycle; printed-circuit board mounted; lead length 4 mm	-	150	-	K/W

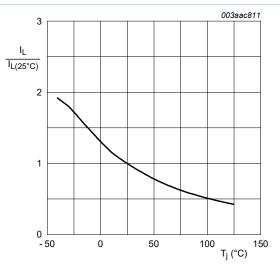


AC Thyristor power switch

### 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA
IL	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	25	mA
		V <sub>D</sub> = 12 V; I <sub>G</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	25	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	20	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	1.3	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 400 V; I <sub>T</sub> = 100 mA; T <sub>j</sub> = 125 °C	0.15	-	-	V
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; T <sub>j</sub> = 25 °C	-	-	0.9	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	2	μA
		V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	-	0.2	mA
V <sub>CL</sub>	clamping voltage	I <sub>CL</sub> = 0.1 mA; t <sub>p</sub> = 1 ms; T <sub>j</sub> ≤ 125 °C	650	-	-	V
Dynamic ch	narateristics			1		
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit; Fig. 10	300	-	-	V/µs
dI <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 1 \text{ A};$ $dV_{com}/dt = 15 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ Fig. 11; Fig. 12	0.15	-	-	A/ms





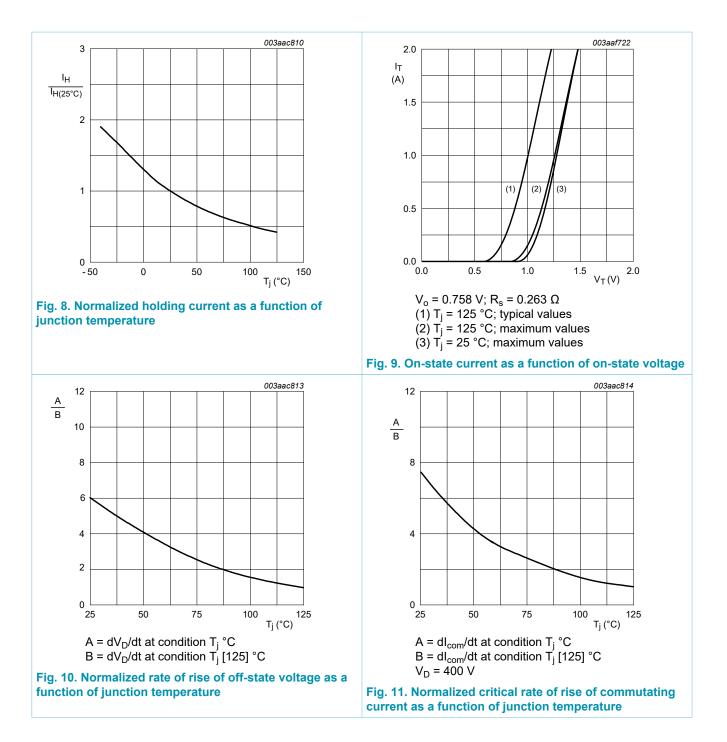


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## ACT108-600D

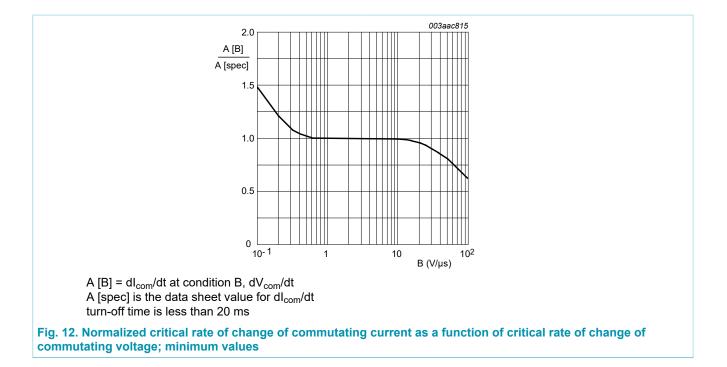
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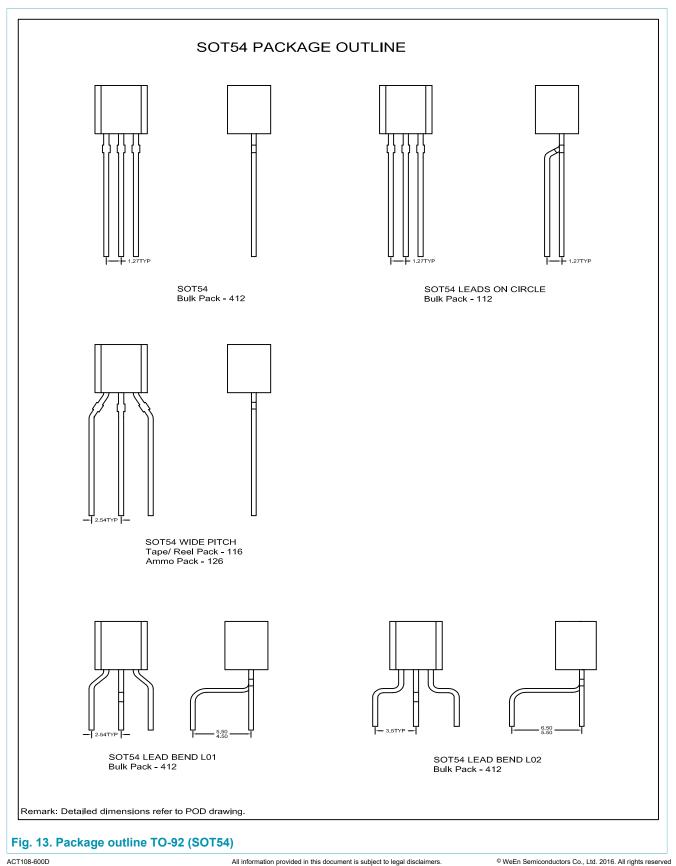
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## 10. Package outline



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#### AC Thyristor power switch

### 11. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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